

Anisotropic Fermi Contours of Electron- and Hole-Flux Composite Fermions

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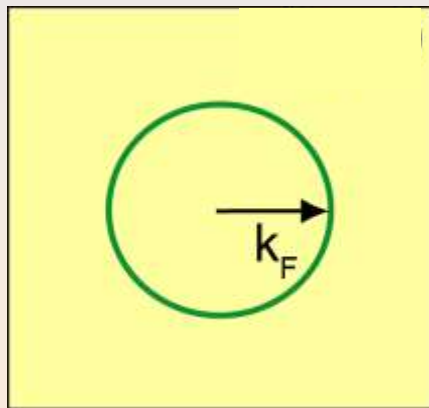
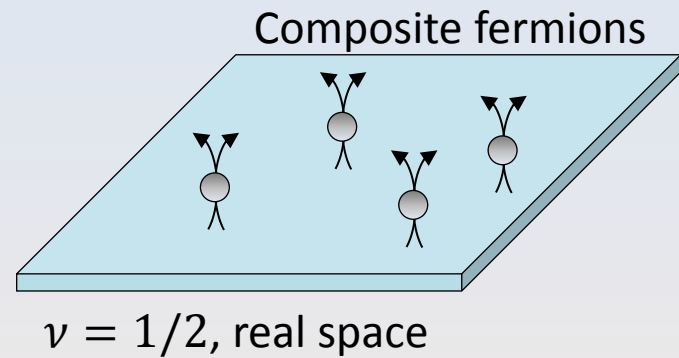
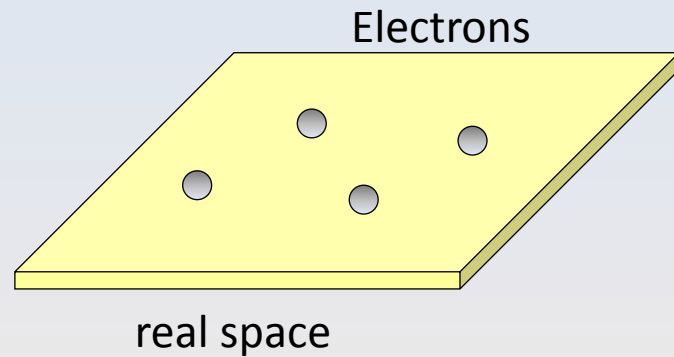
Sample growth: Loren Pfeiffer, Kenneth West, Kirk Baldwin, J. J. D. Lee

Theoretical calculations: Roland Winkler*

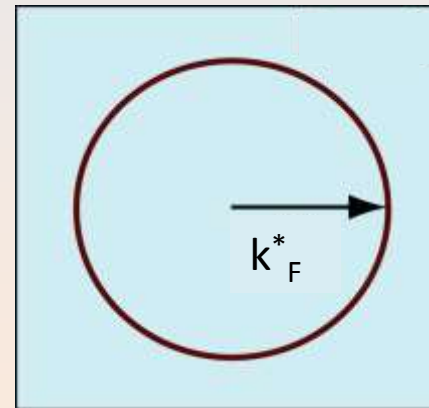
* Department of Physics, Northern Illinois University



Composite fermions

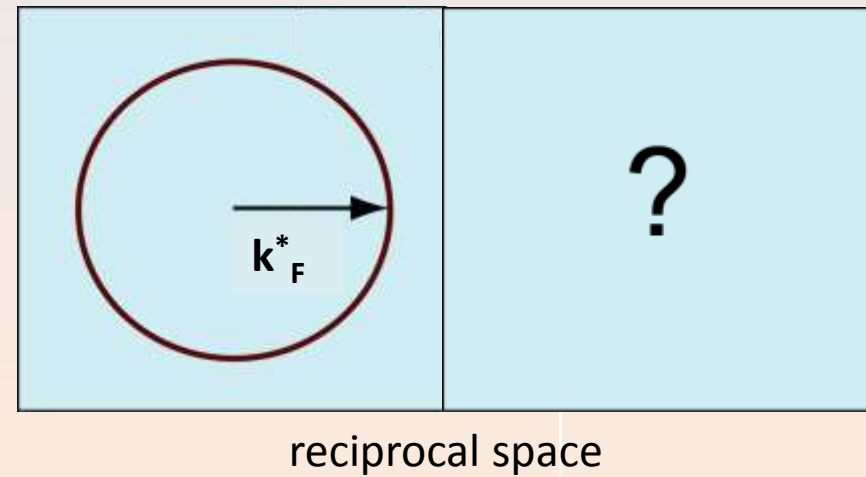
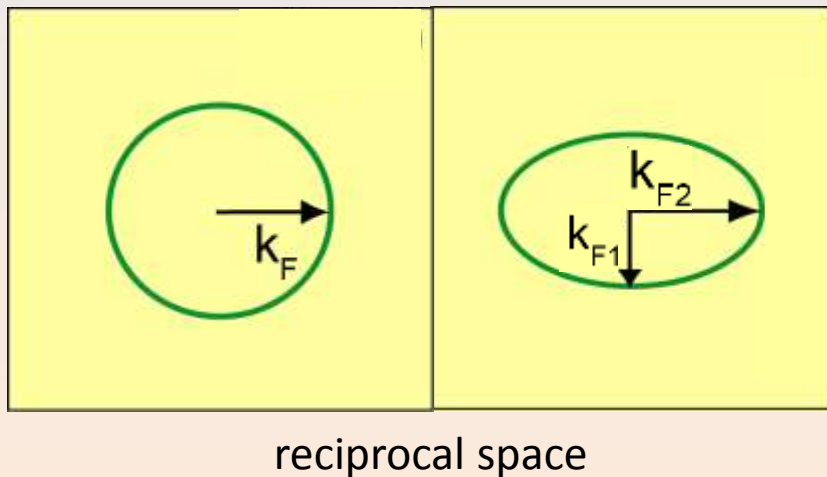
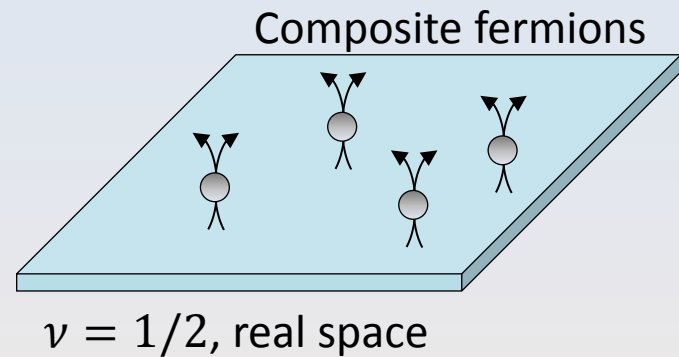
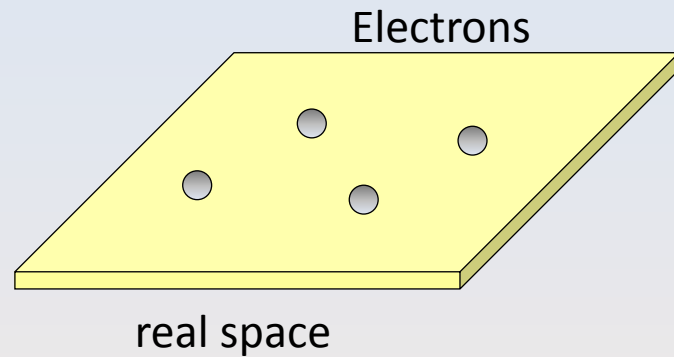


reciprocal space

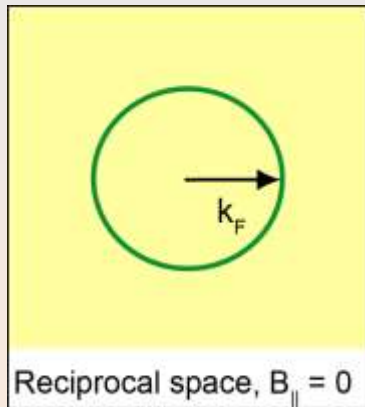
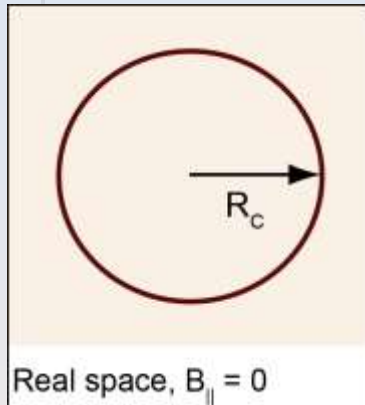


reciprocal space

Composite fermions

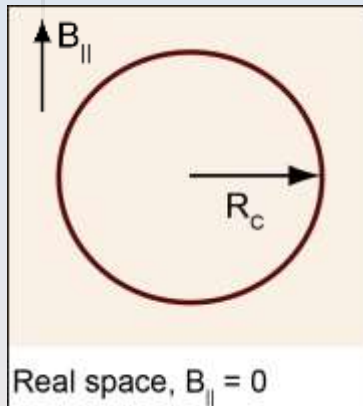


Tuning the Fermi contour shape

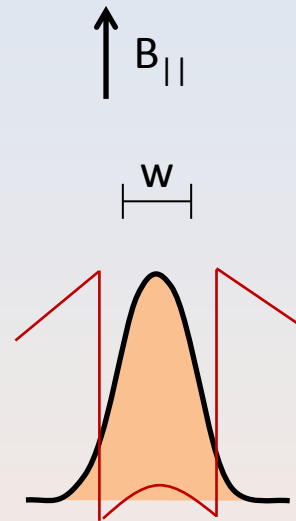
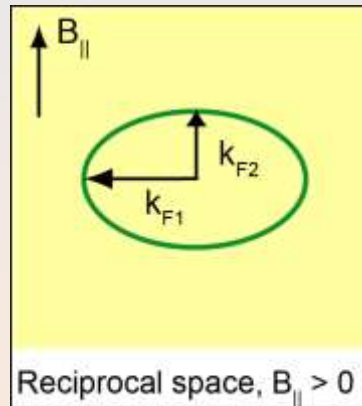
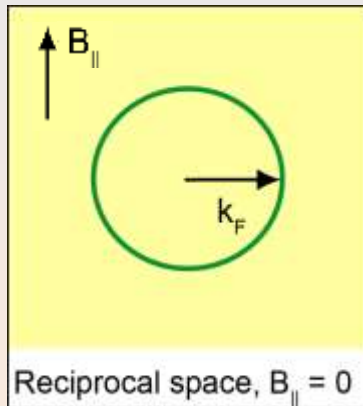
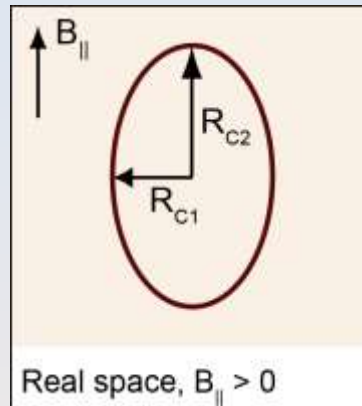


Tuning the Fermi contour shape

zero thickness

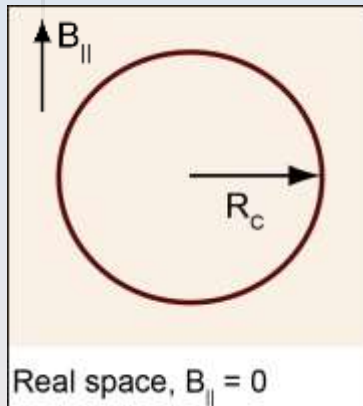


finite thickness

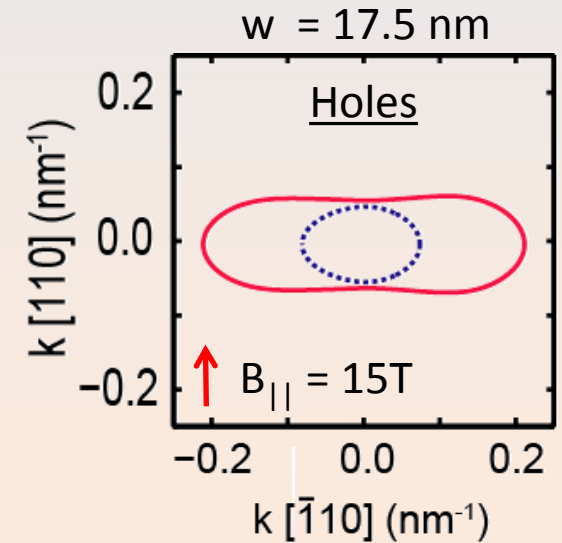
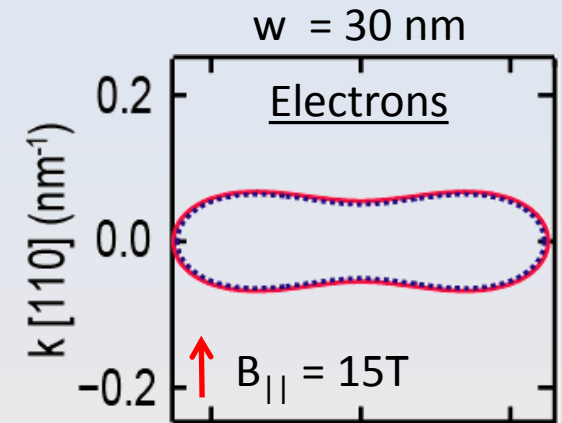
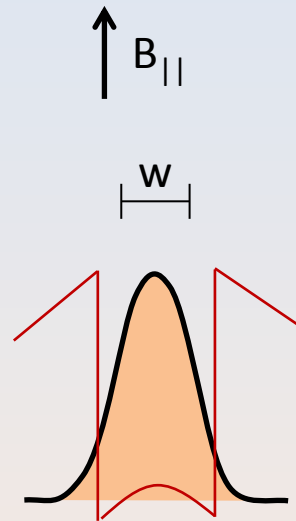
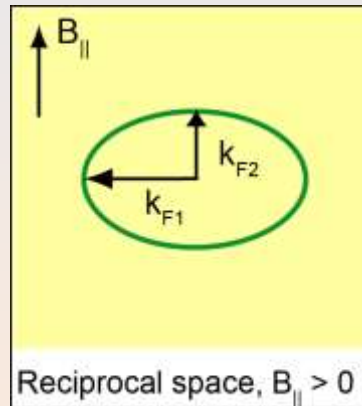
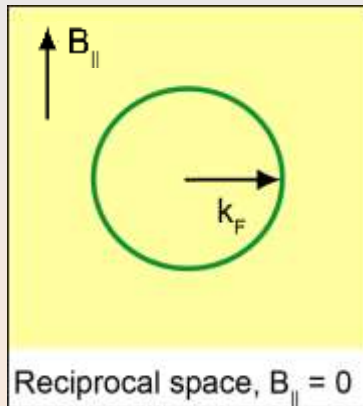
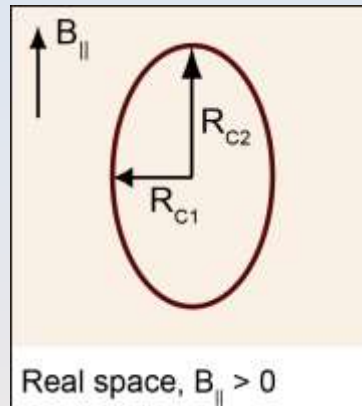


Fermi contour distortion in parallel field

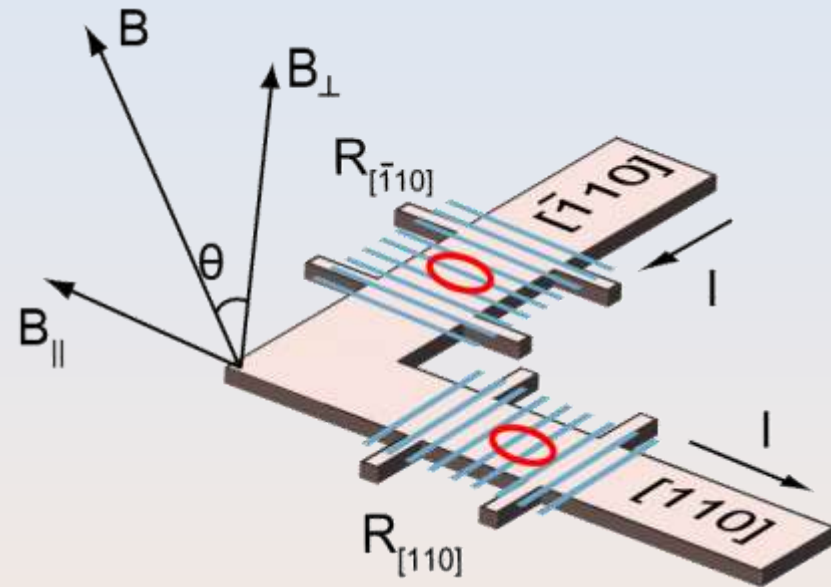
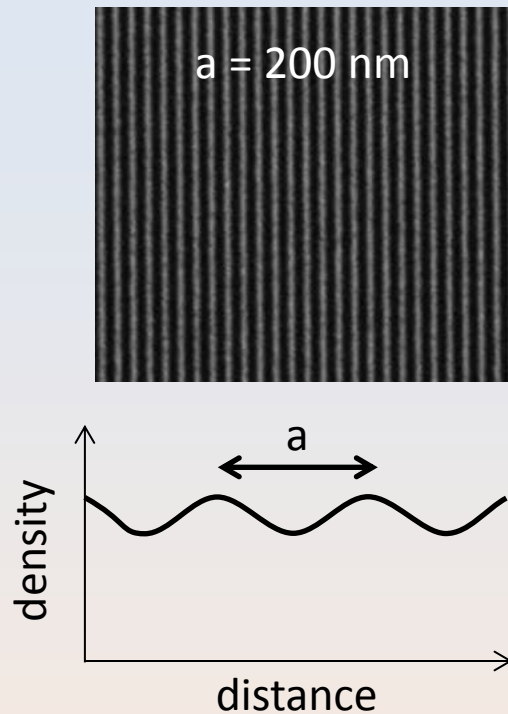
zero thickness



finite thickness



Measuring Fermi contour shape: commensurability oscillations

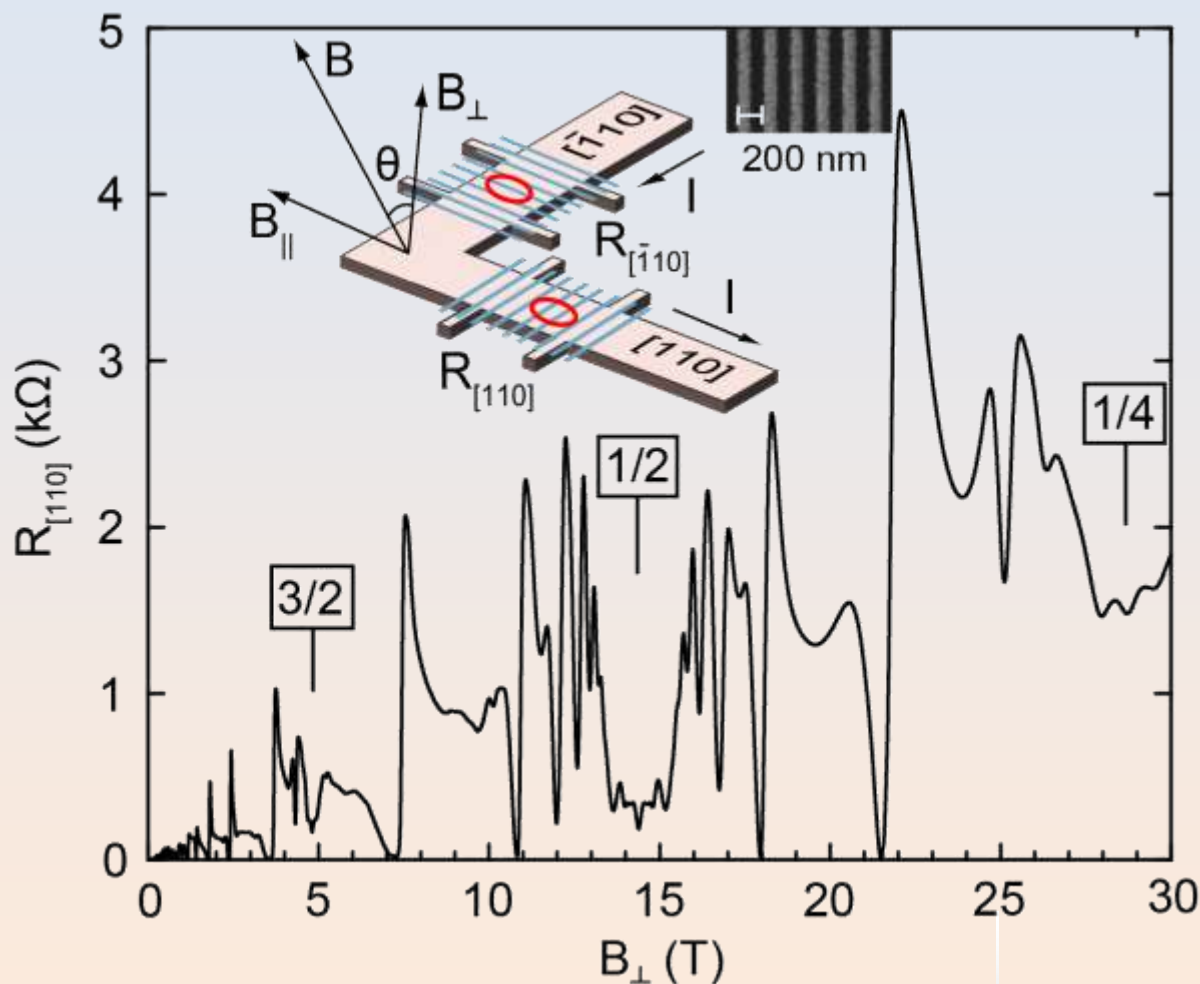


- Negative e-beam resist
- Piezo-electric effect in GaAs
- Periodic density modulation
- Keep sample tilt fixed
- Sweep field & take data
- Simultaneously measure $R_{[110]}$ & $R_{[\bar{1}10]}$

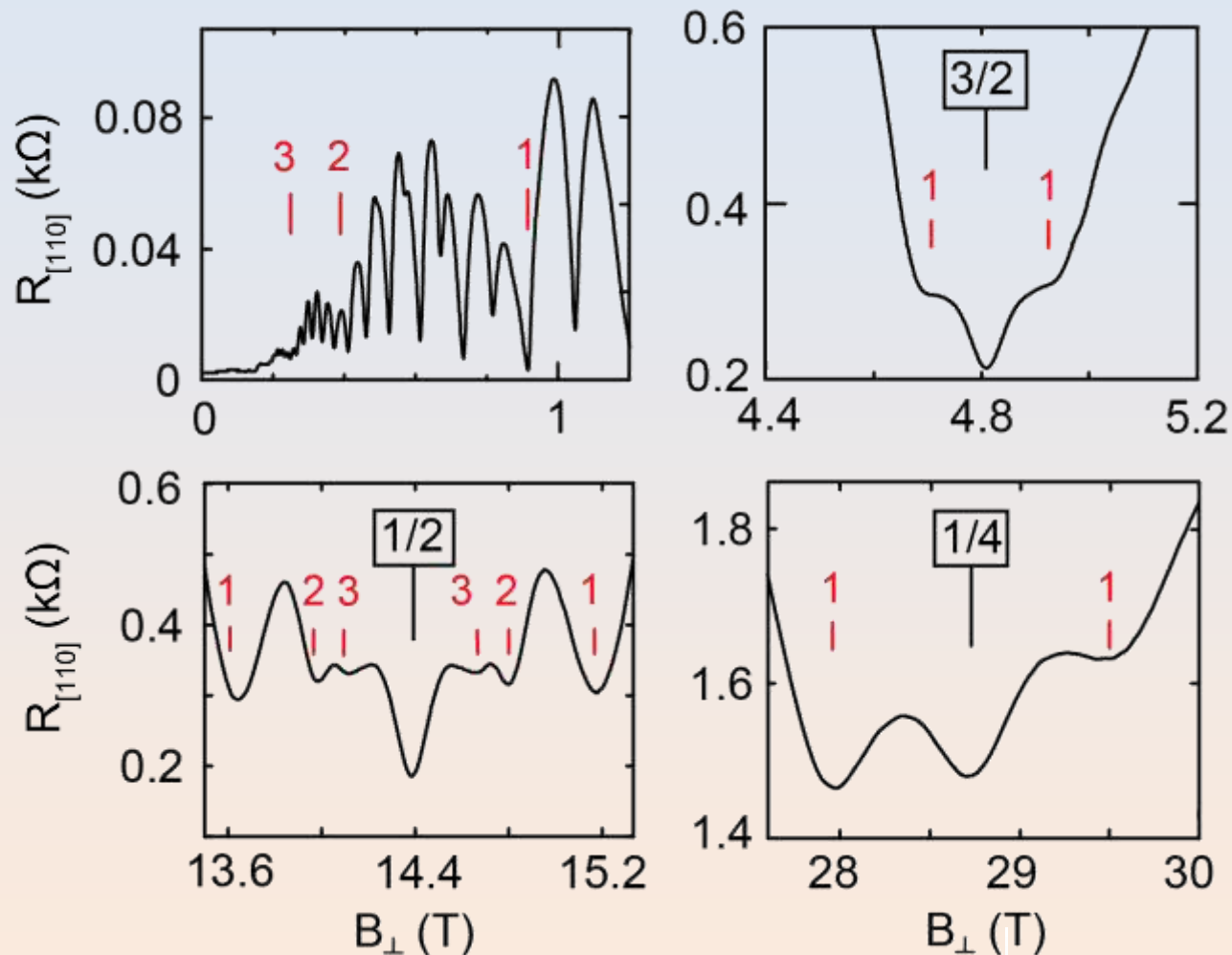
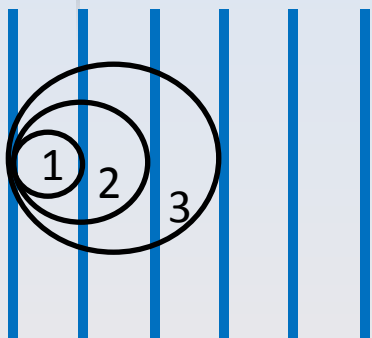
Composite fermion commensurability oscillations

$T = 300 \text{ mK}$
 $n = 1.8 \times 10^{11} \text{ cm}^{-2}$

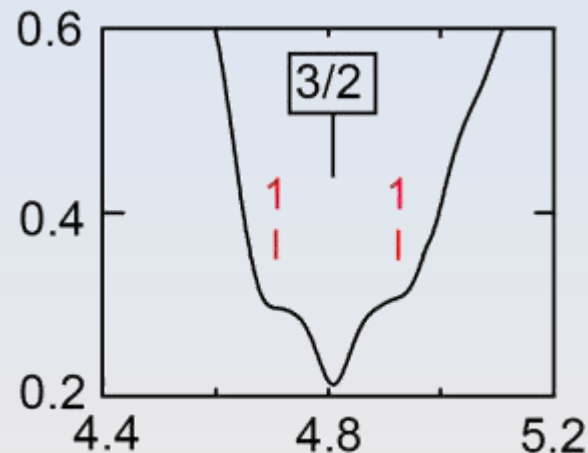
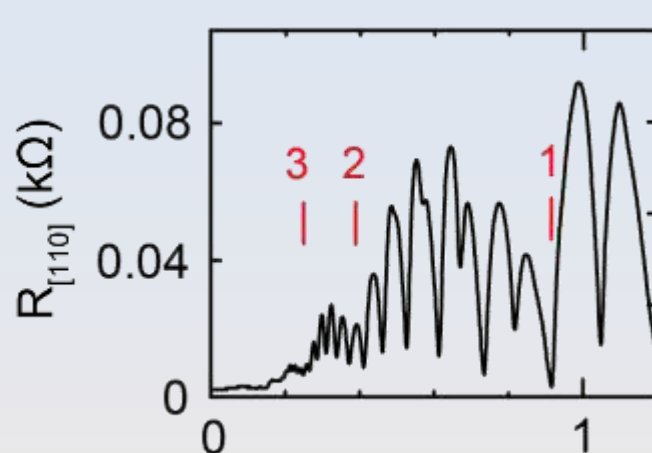
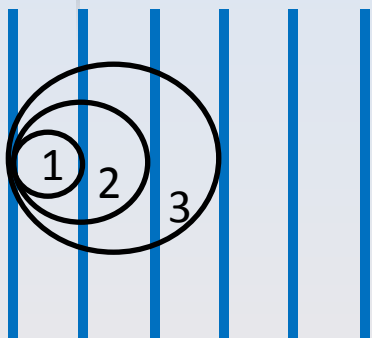
Si δ	cap layer 95 nm
	$\text{Al}_x\text{Ga}_{1-x}\text{As}$ 95 nm
	GaAs, $W = 40 \text{ nm}$
	$\text{Al}_x\text{Ga}_{1-x}\text{As}$ 95 nm
Si δ	(100) GaAs substrate



Composite fermion commensurability oscillations



Composite fermion commensurability oscillations

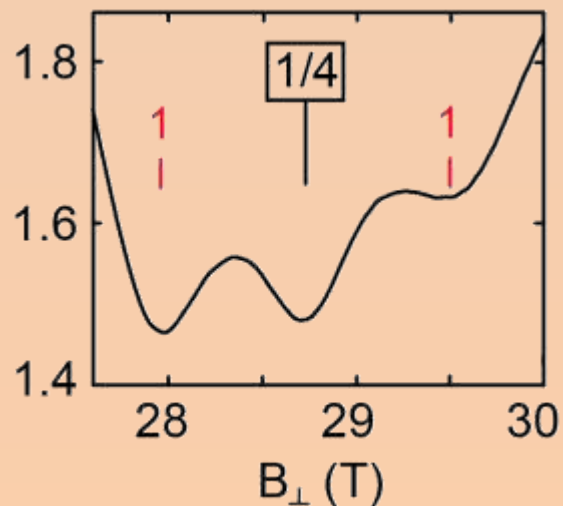
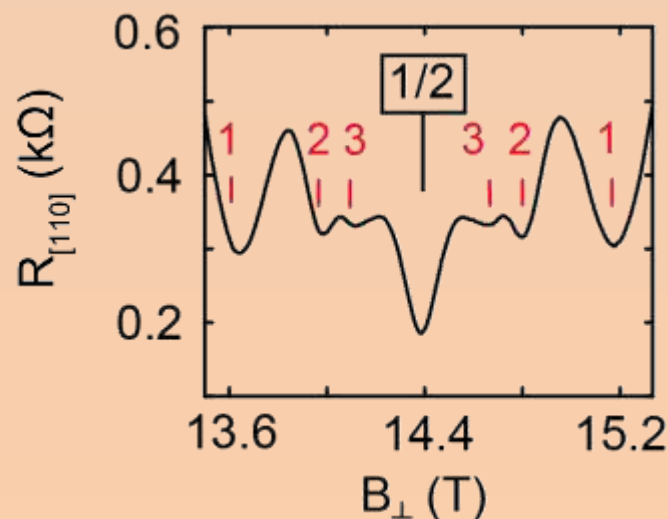


$$\frac{2R_C}{a} = i + \frac{1}{4}$$

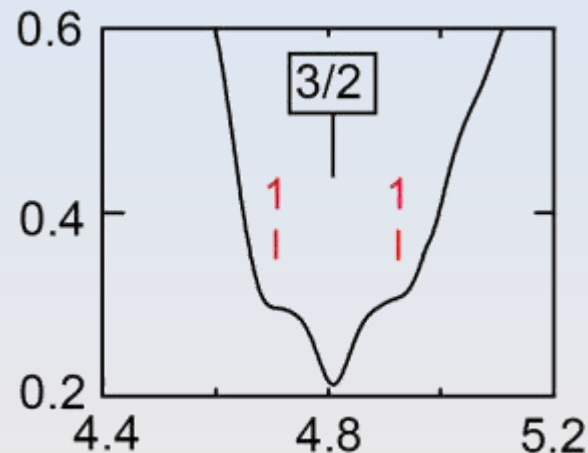
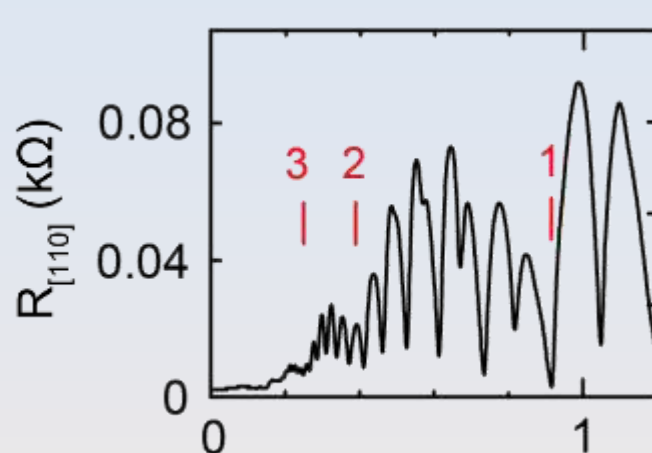
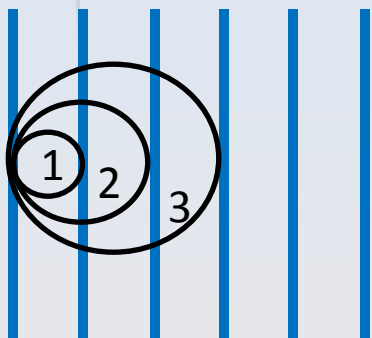
$$i = 1, 2, 3 \dots$$

$$2R_C = \frac{2\hbar k_F}{eB}$$

$$k_F = \sqrt{4\pi n}$$



Composite fermion commensurability oscillations

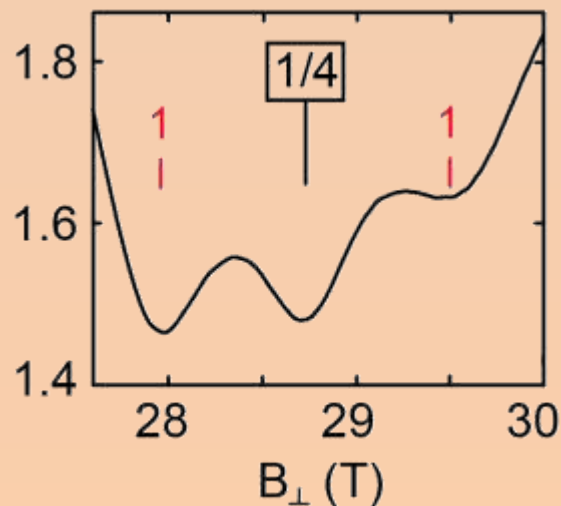
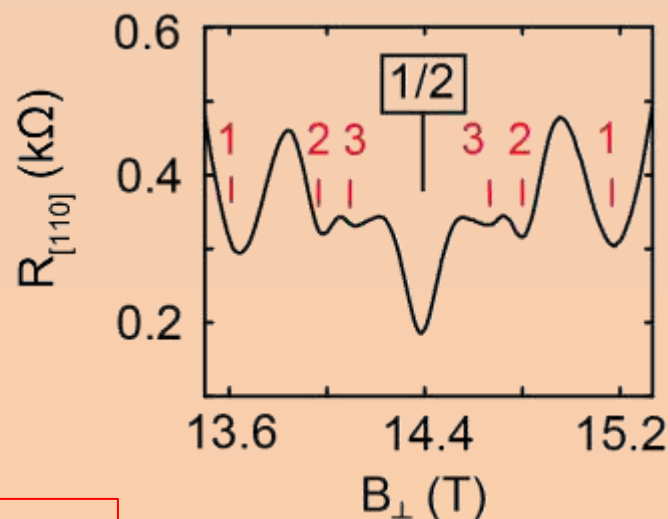


$$\frac{2R_C}{a} = i + \frac{1}{4}$$

$$i = 1, 2, 3 \dots$$

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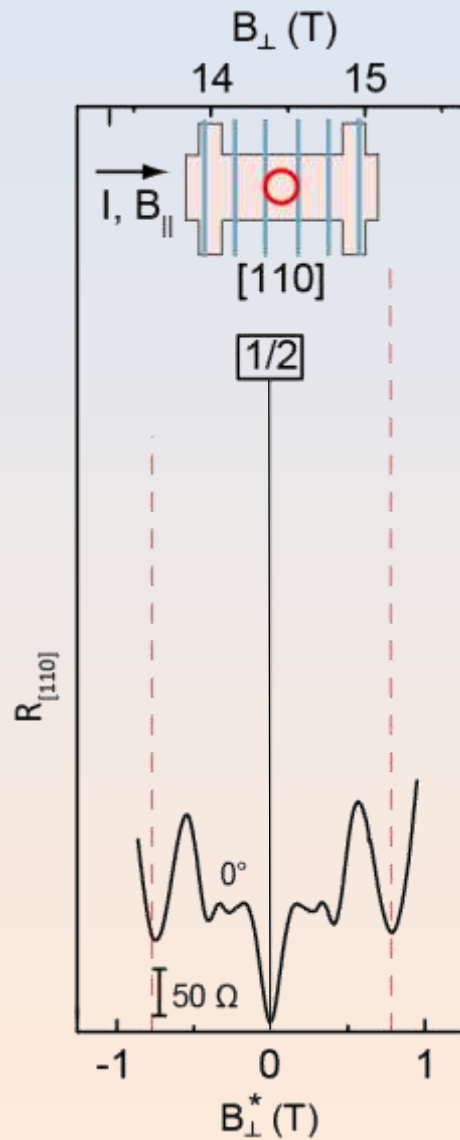
$$k_F^* = \frac{5}{8} \frac{eaB^*}{\hbar}$$



Composite fermion commensurability oscillations

$T = 300 \text{ mK}$
 $w = 40 \text{ nm}$
 $n = 1.8 \times 10^{11} \text{ cm}^{-2}$
 $a = 200 \text{ nm}$

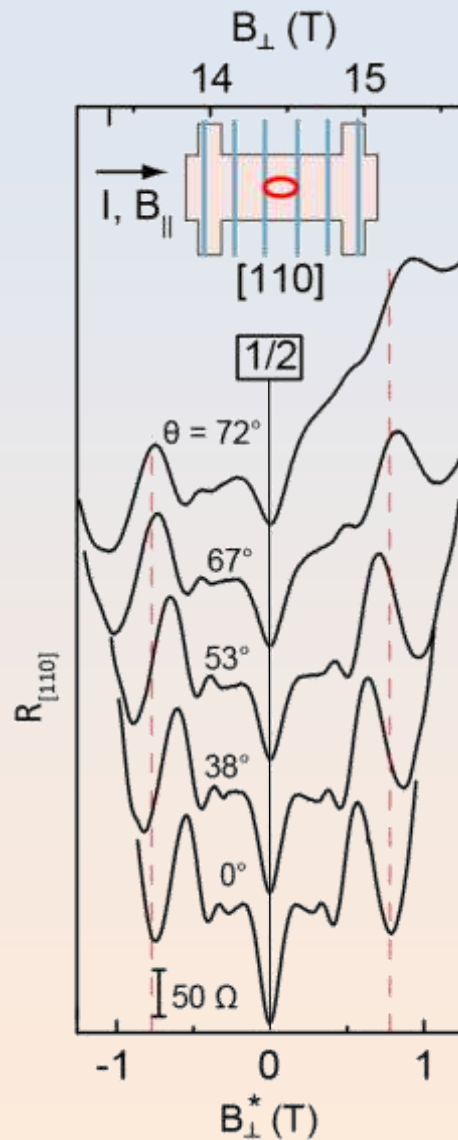
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Composite fermion commensurability oscillations

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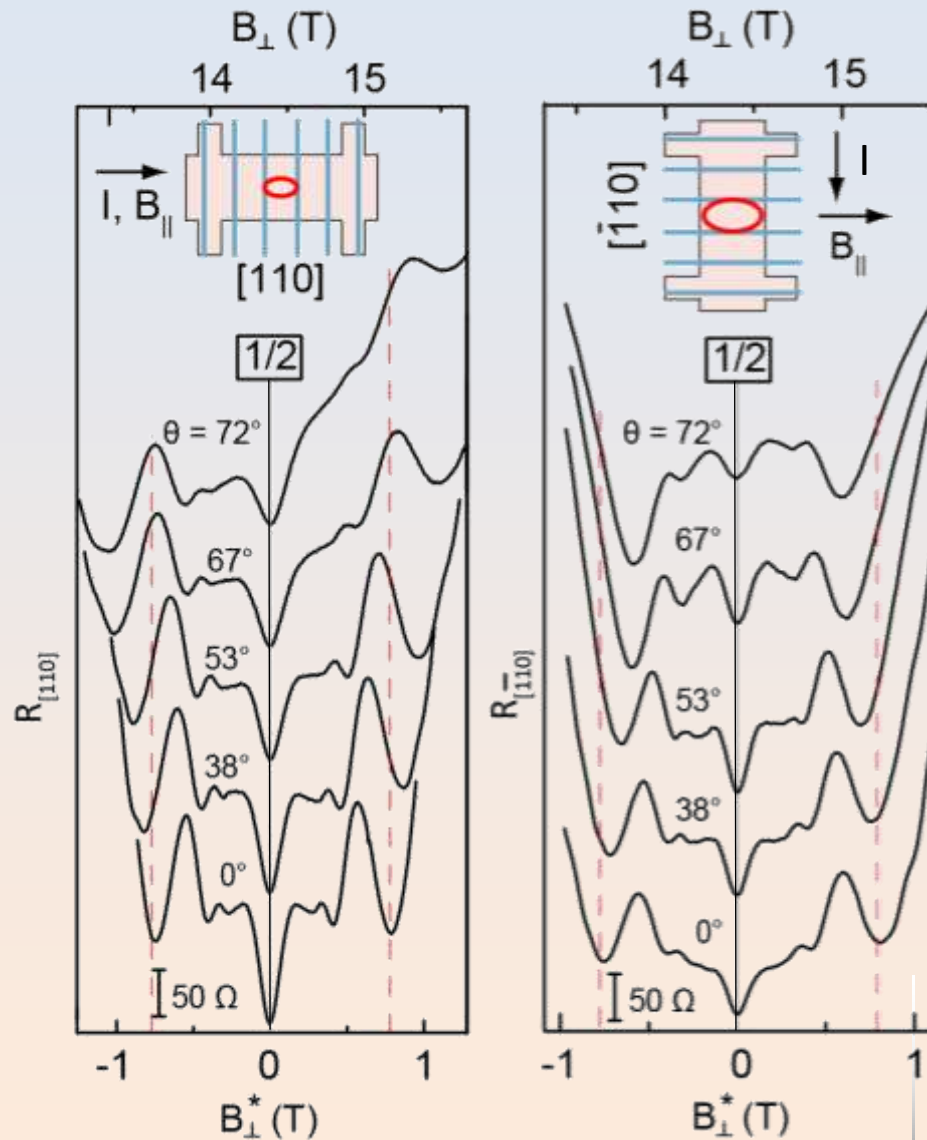
$$k_F^* = \frac{5}{8} \frac{eaB^* i=1}{\hbar}$$



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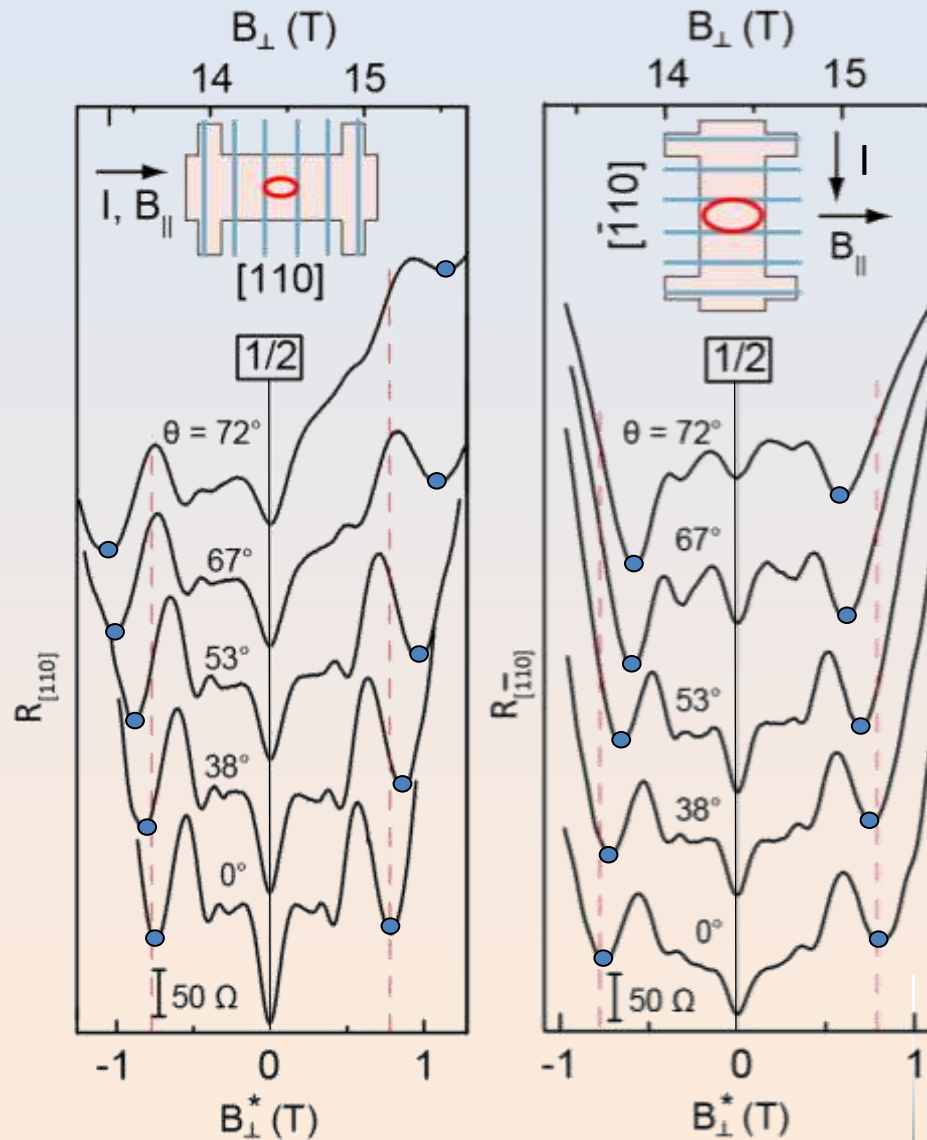
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Composite fermion commensurability oscillations

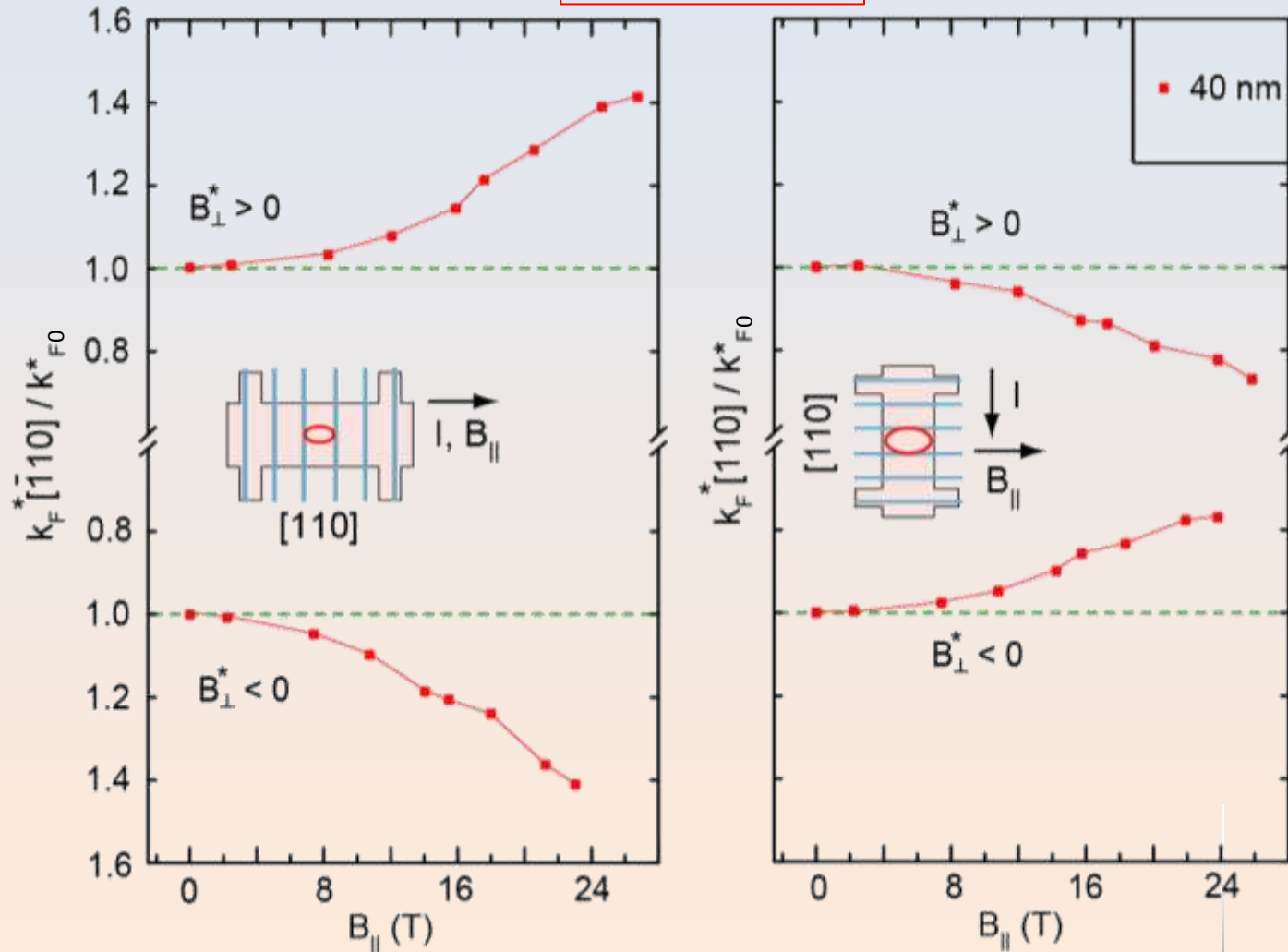
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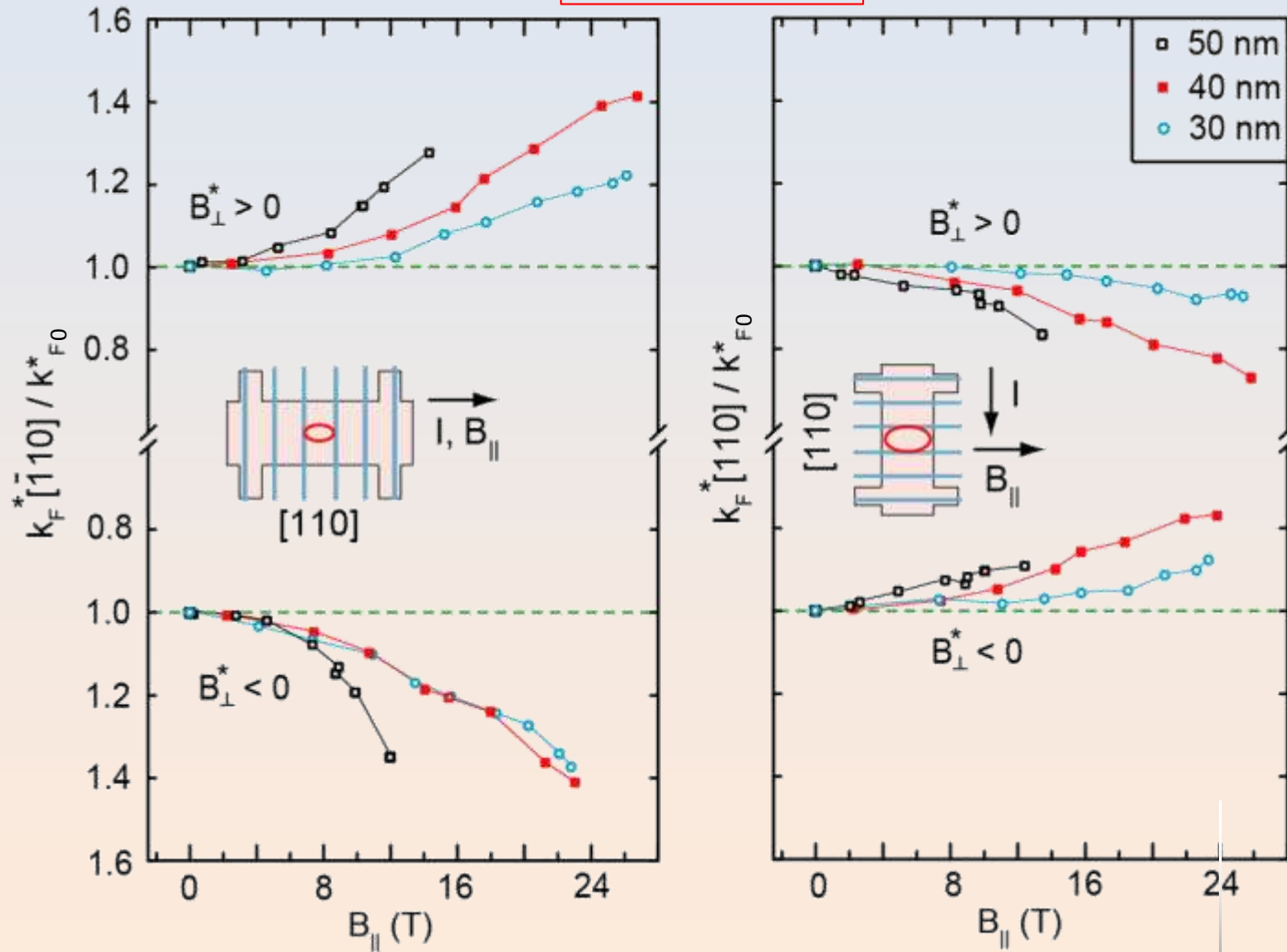
Composite fermion Fermi wave vectors

$$k_F^* = \frac{5}{8} \frac{eaB_{i=1}}{\hbar}$$

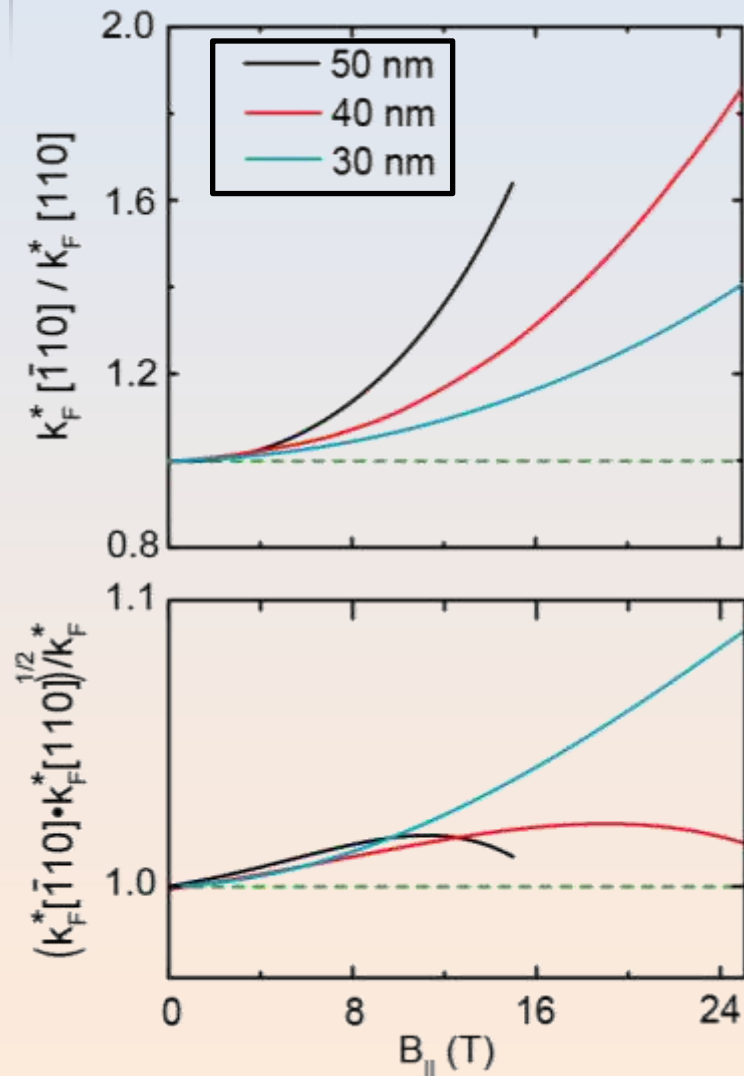


Composite fermion Fermi wave vectors

$$k_F^* = \frac{5}{8} \frac{eaB_{i=1}}{\hbar}$$

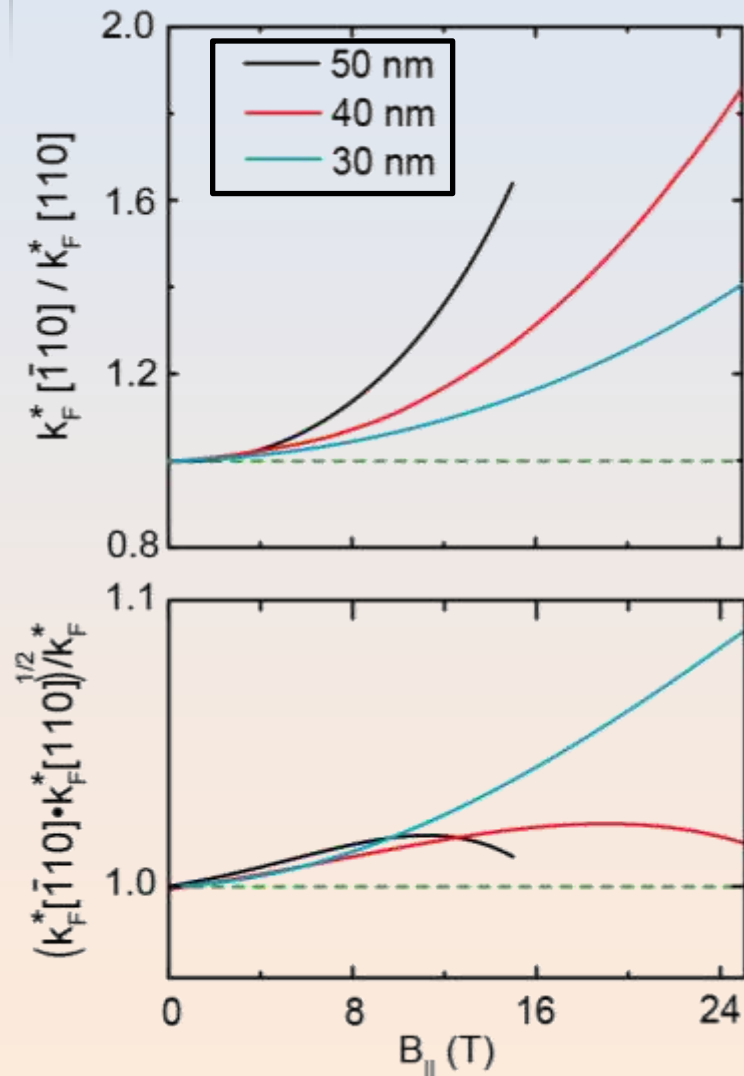


Composite fermion Fermi contour anisotropy



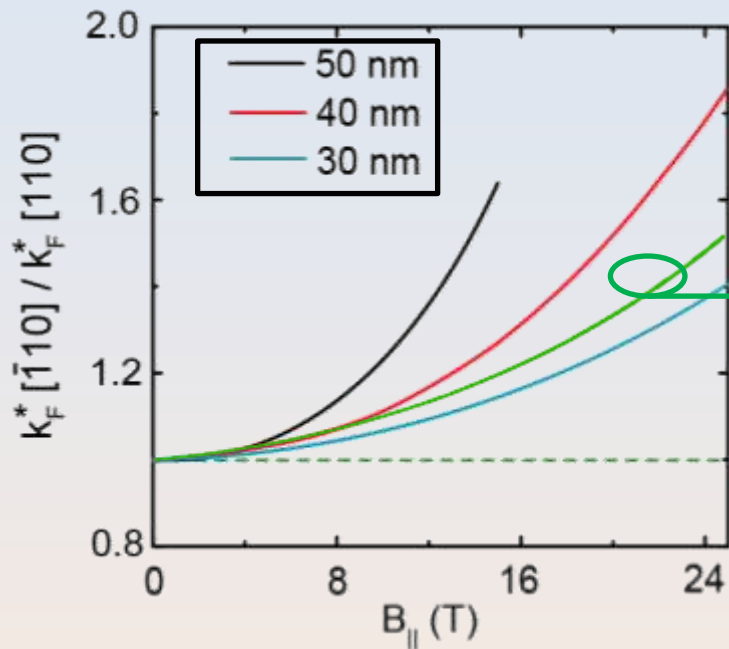
- $B_{||}$ -induced anisotropy
- Well-width dependence
- Consistent with elliptical shape

Composite fermion Fermi contour anisotropy



- $B_{||}$ -induced anisotropy
- Well-width dependence
- Consistent with elliptical shape
- Lack of theoretical calculations

Composite fermion Fermi contour anisotropy



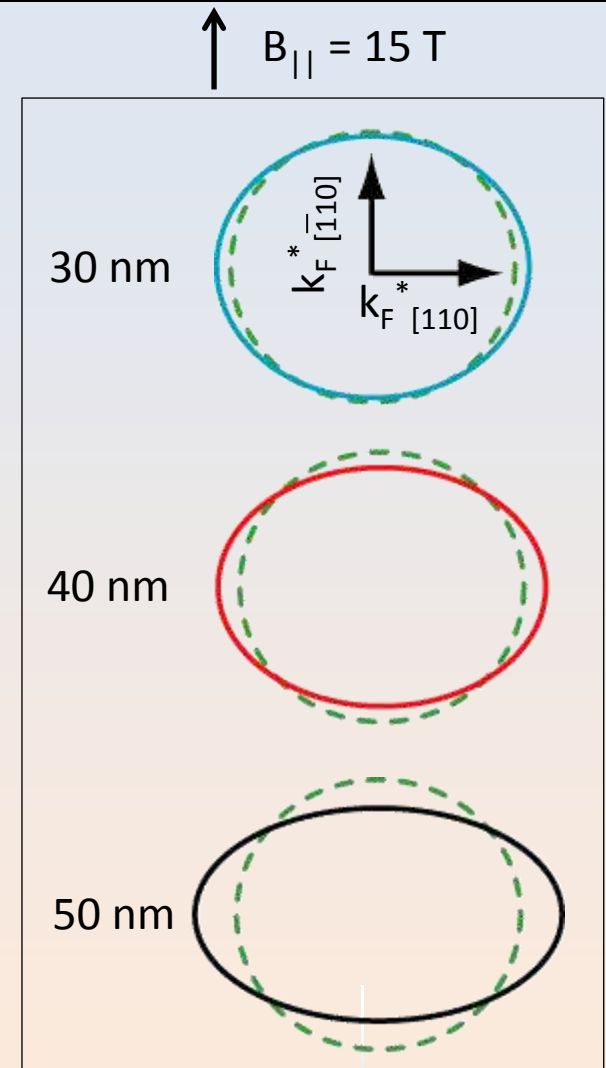
- $B_{||}$ -induced anisotropy
- Well-width dependence

Hole-flux CFs
w = 17.5 nm

- Importance of band structure

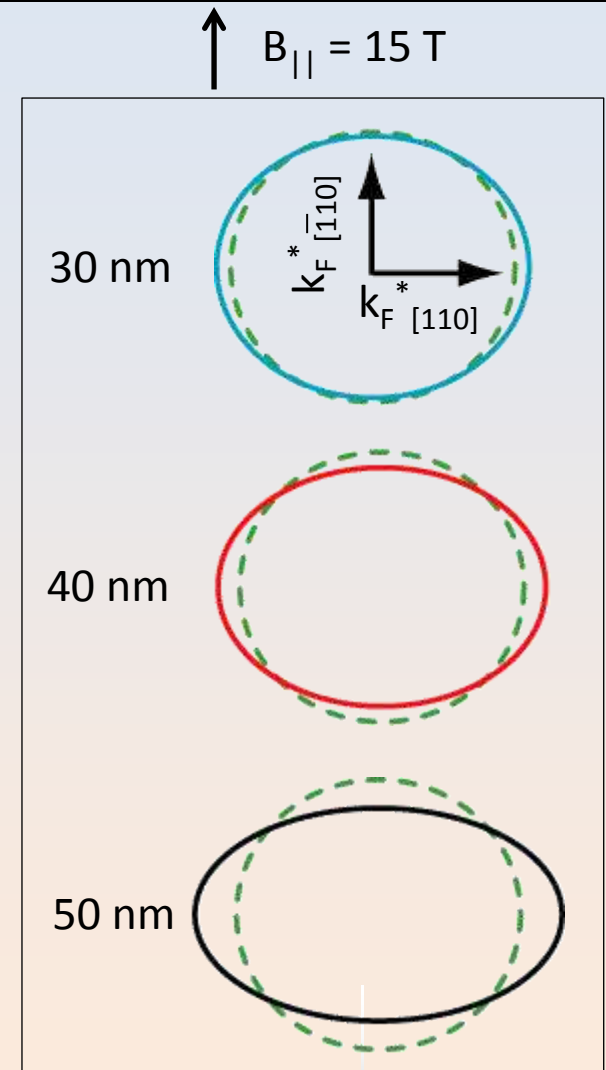
Summary

- Direct evidence of composite fermion Fermi contour **anisotropy**
- **Tunability** with parallel field
- Strong dependence on **carrier layer thickness**
- Dependence on **band structure**



Summary

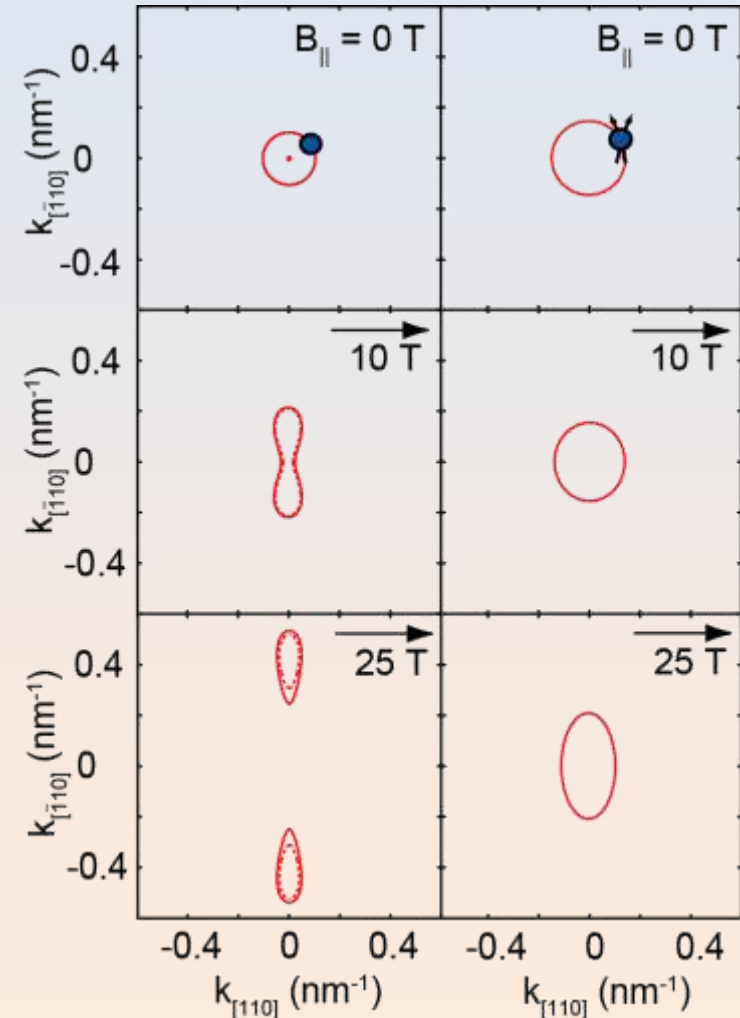
- Direct evidence of composite fermion Fermi contour **anisotropy**
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- **Very different from 2D electrons**



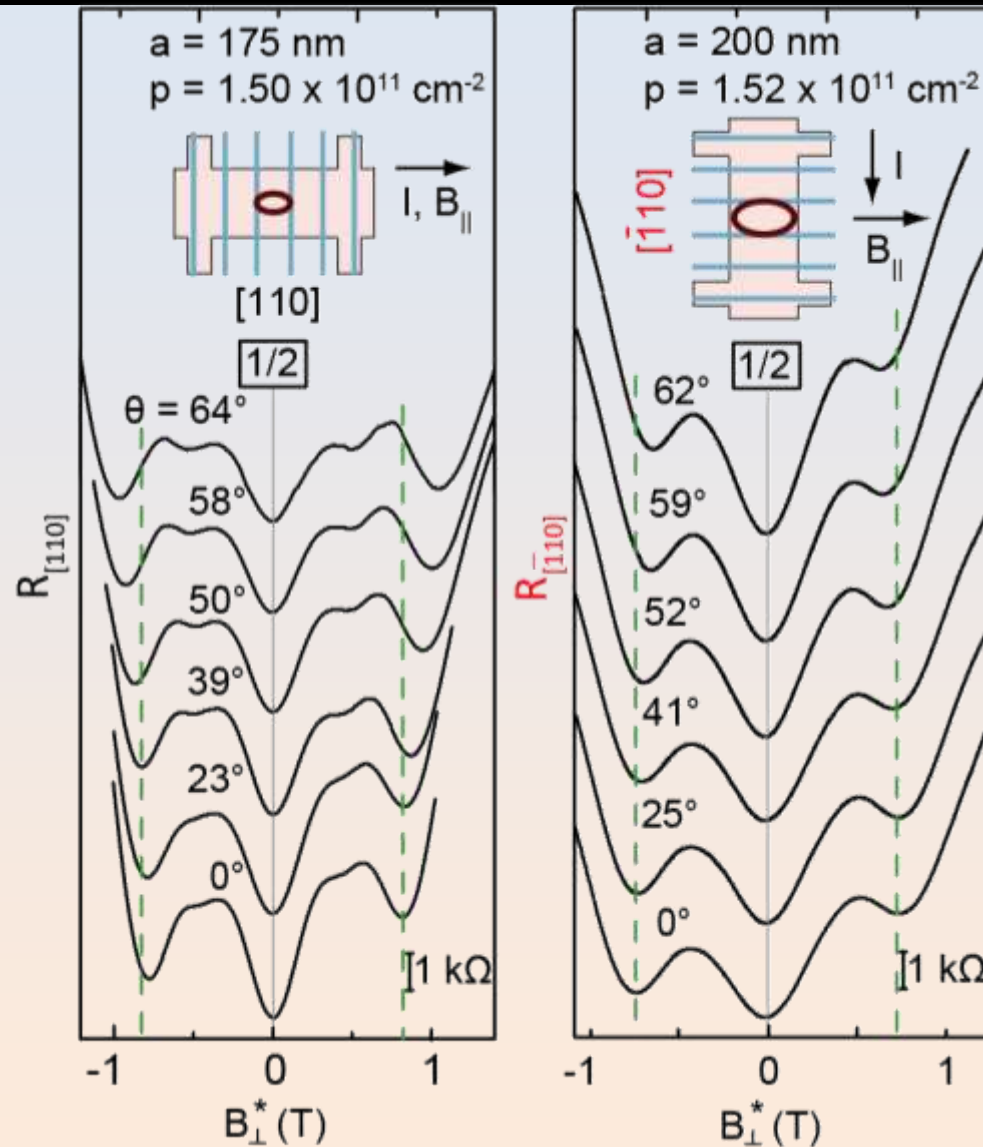
Summary

- Direct evidence of composite fermion Fermi contour **anisotropy**
- **Tunability** with parallel field
- Strong dependence on **carrier layer thickness**
- Dependence on **band structure**
- **Very different from 2D electrons**

$w = 40 \text{ nm}$, $n = 1.7 \times 10^{11} \text{ cm}^{-2}$
electrons CFs



Hole-flux composite fermion Fermi contour size



Hole-flux composite fermion Fermi contour size

